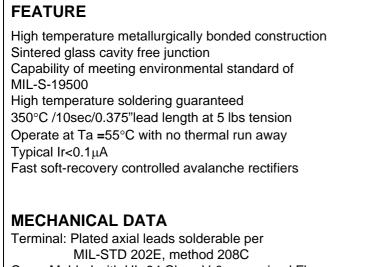
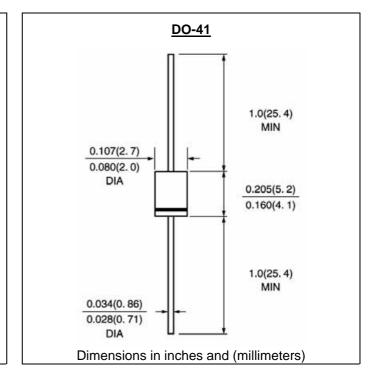
BYV26AGP THRU BYV26EGP

SINTERED GLASS JUNCTION ULTRA FAST SWITCHING RECTIFIER VOLTAGE : 200V to 1000V CURRENT: 1.0A





MIL-STD 202E, method 208C Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy Polarity: color band denotes cathode Mounting position: any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

	SYMBOL	BYV26A GP	BYV26B GP	BYV26C GP	BYV26D GP	BYV26E GP	units
Maximum Recurrent Peak Reverse Voltage	Vrrm	200	400	600	800	1000	V
Maximum RMS Voltage	Vrms	140	280	420	560	700	V
Maximum DC blocking Voltage	Vdc	200	400	600	800	1000	V
Maximum Average Forward Rectified Current 3/8"lead length at Ta =55°C	lf(av)	1.0					А
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	lfsm	30					А
Maximum Forward Voltage at rated Forward Current and 50°C	Vf	2.5					V
non-repetitive peak reverse avalanche energy (Note 1)	Ersm	10					mJ
Maximum DC Reverse CurrentTa = $25^{\circ}C$ at rated DC blocking voltageTa = $150^{\circ}C$	lr	5.0 150.0					μΑ μΑ
Maximum Reverse Recovery Time (Note 2)	Trr	30 75			nS		
Typical Junction Capacitance (Note 3)	Cj	15.0					pF
Typical Thermal Resistance (Note 4)	R ja	55.0					°C /w
Storage and Operating Junction Temperature	Tstg, Tj	-65 to +175					°C

Note:

1. R=400mA; Tj=Tjmax prior to surge; inductive load switched off

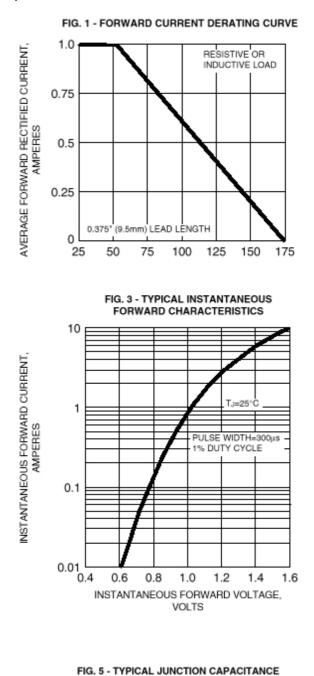
2. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A

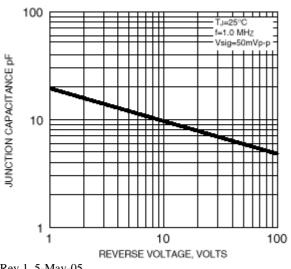
3. Measured at 1.0 MHz and applied reverse voltage of 4.0 Vdc

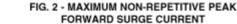
4. Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted

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RATINGS AND CHARACTERISTIC CURVES BYV26AGP THRU BYV26EGP







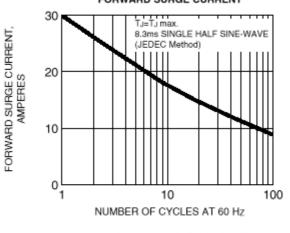
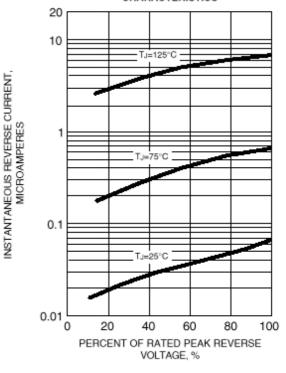
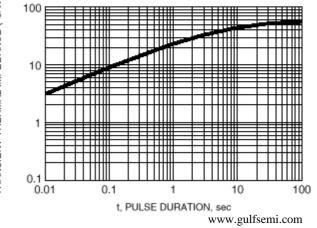


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS







FRANSIENT THERMAL IMPEDANCE (°C/W)

Rev.1, 5-May-05